

# High-gain Amplifier Transistor (32V, 0.3A)

## 2SD1383K

#### Features

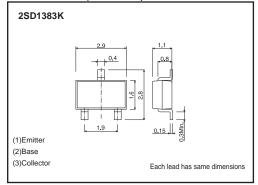
- 1) Darlington connection for high DC current gain.
- 2) Built-in  $4k\Omega$  resistor between base and emitter.
- 3) Complements the 2SB852K.

#### Packaging specifications

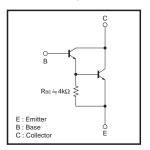
Туре	2SD1383K
Package	SMT3
hfE	В
Marking	W*
Code	T146
Basic ordering unit (pieces)	3000

<sup>\*</sup> Denotes her

#### ●Dimensions (Unit: mm)



#### ●Circuit diagram



#### ● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit		
Collector-base voltage	Vсво	40	V		
Collector-emitter voltage	Vces	32	V *1		
Emitter-base voltage	Vево	6	V		
Collector current	lc	0.3	A (DC)		
		1.5	A (Pulse) *2		
Collector power dissipation	Pc	0.2	W		
Junction temperature	Tj	150	°C		
Storage temperature	Tstg	-55 to +150	°C		

<sup>\*1</sup> R<sub>BE</sub>=0Ω \*2 Single pulse Pw=10ms

### ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	40	_	_	V	Ic=100μA
Collector-emitter breakdown voltage	BVces	32	_	_	V	Ic= $-1$ mA , R <sub>BE</sub> = $0$ $\Omega$
Emitter-base breakdown voltage	ВVево	6	_	_	V	Iε=100μA
Collector cutoff current	Ісво	_	_	1	μΑ	Vcb=24V
Emitter cutoff current	<b>І</b> ЕВО	_	_	1	μΑ	V <sub>EB</sub> =4.5V
DC current transfer ratio	hfe	5000	_	_	_	Vce=5V, Ic=0.1A
Collector-emitter saturation voltage	VCE(sat)	_	_	1.5	V	Ic=200mA, I <sub>B</sub> =0.4mA *1
Transition frequency	f⊤	_	250	_	MHz	VcE=5V, IE= -10mA, f=100MHz *2
Output capacitance	Cob	_	3	_	pF	Vcb=10V, Ie=0A, f=1MHz

<sup>\*1</sup> Measured using pulse current. \*2 Transition frequency of the device.

2SD1383K Data Sheet

#### ●Electrical characteristic curves

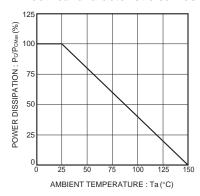


Fig.1 Power dissipation curves

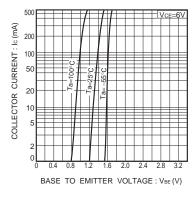


Fig.2 Ground emitter propagation characteristisc

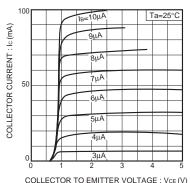


Fig.3 Ground emitter output characteristics

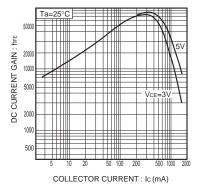


Fig.4 DC current gain vs. collector current (I)

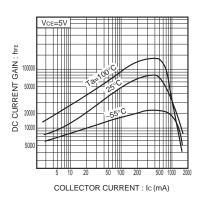


Fig.5 DC current gain vs. collector current (  $\rm II$  )

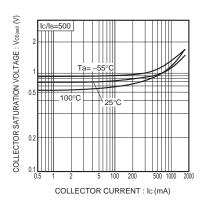


Fig.6 Collector-emitter saturation voltage vs. collector current

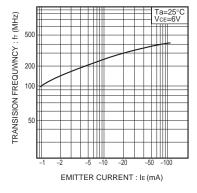


Fig.7 Gain bandwidth product vs. emitter current

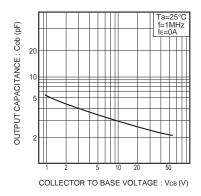


Fig.8 Collector output capacitance vs. collector-base voltage

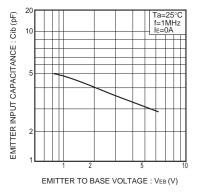


Fig.9 Emitter input capacitance vs. emitter-base voltage

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